

# PD84006-E

## RF power transistor, LdmoST plastic family N-channel enhancement-mode lateral MOSFETs

#### Datasheet -production data

### Features

- Excellent thermal stability
- Common source configuration
- Broadband performances: P<sub>OUT</sub> = 6 W with 13 dB gain @ 870 MHz
- Plastic package
- ESD protection
- In compliance with the 2002/95/EC European directive

## Description

The PD84006-E is a common source N-channel, enhancement-mode lateral field-effect RF power transistor. It is designed for high gain, broadband commercial and industrial applications. It operates at 7 V in common source mode at frequencies of up to 1 GHz boasts the excellent gain, linearity and reliability of ST's latest LDMOS technology mounted in the first true SMD plastic RF power package, PowerSO-10RF 's superior linearity performance makes it an ideal solution for portable radio and UHF RFID reader. The PowerSO-10 plastic package, designed to offer high reliability, is the first ST JEDEC approved, high power SMD package. It has been specially optimized for RF needs and offers excellent RF performances and ease of assembly.



Figure 1. Pin connections



#### Table 1. Device summary

Order code	Package	Packaging	
PD84006-E	PowerSO-10RF (formed lead)	Tube	

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This is information on a product in full production.

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# 1 Electrical data

## 1.1 Maximum ratings

(T<sub>CASE</sub> = 25 °C)

### Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>(BR)DSS</sub>	Drain-source voltage	25	V
V <sub>GS</sub>	Gate-source voltage	-0.5 to +15	V
I <sub>D</sub>	Drain current	5	A
P <sub>DISS</sub>	Power dissipation (@ T <sub>C</sub> = 70 °C)	59	W
TJ	Max. operating junction temperature	165	°C
T <sub>STG</sub>	Storage temperature	-65 to +150	°C

## 1.2 Thermal data

### Table 3.Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJC</sub>	Junction - case thermal resistance	1.6	°C/W



# 2 Electrical characteristics

T<sub>CASE</sub> = +25 °C

### 2.1 Static

### Table 4. Static

Symbol	Test conditions				Тур	Max	Unit
I <sub>DSS</sub>	$V_{GS} = 0V$	V <sub>DS</sub> = 25 V				1	μA
I <sub>GSS</sub>	$V_{GS} = 5 V$	$V_{DS} = 0 V$				1	μA
V <sub>GS(Q)</sub>	V <sub>DS</sub> = 10 V	l <sub>D</sub> = 150 mA		3.0		4.3	V
V <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 1 A			0.34		V
C <sub>ISS</sub>	$V_{GS} = 0V$	$V_{DS} = 7 V$	f = 1 MHz		40		pF
C <sub>OSS</sub>	$V_{GS} = 0V$	$V_{DS} = 7 V$	f = 1 MHz		33		pF
C <sub>RSS</sub>	$V_{GS} = 0V$	$V_{DS} = 7 V$	f = 1 MHz		1.45		pF

## 2.2 Dynamic

### Table 5. Dynamic

Symbol	Test conditions	Min	Тур	Max	Unit
P <sub>3</sub> dB	$V_{DD} = 7.5 \text{ V}, I_{DQ} = 150 \text{ mA}$ f = 870 MHz	5	6		W
G <sub>P</sub>	$V_{DD}$ = 7.5 V, $I_{DQ}$ = 150 mA, $P_{OUT}$ = 2 W, f = 870 MHz	15		-	dB
h <sub>D</sub>	$V_{DD}$ = 7.5 V, $I_{DQ}$ = 150 mA, $P_{OUT}$ = $P_3$ dB, f = 870 MHz	50	60		%
Load mismatch	$V_{DD}$ = 9.5 V, $I_{DQ}$ = 150 mA, $P_{OUT}$ = 8 W, f = 870 MHz All phase angles	20:1			VSWR

## 2.3 ESD protection characteristics

### Table 6. ESD protection characteristics

Test conditions	Class
Human body model	2
Machine model	M3



## **3** Typical performances



#### Figure 6. Output power vs. frequency and supply voltage Pin = 24 dBm, Idq = 200 mA





# 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.



able 7.	PowerSO-TORF formed lead (guil wing) mechanical data							
Dim.		mm.		Inch.				
	Min	Тур	Max	Min	Тур	Max		
A1	0	0.05	0.1	0.	0.0019	0.0038		
A2	3.4	3.5	3.6	0.134	0.137	0.142		
A3	1.2	1.3	1.4	0.046	0.05	0.054		
A4	0.15	0.2	0.25	0.005	0.007	0.009		
а		0.2			0.007			
b	5.4	5.53	5.65	0.212	0.217	0.221		
С	0.23	0.27	0.32	0.008	0.01	0.012		
D	9.4	9.5	9.6	0.370	0.374	0.377		
D1	7.4	7.5	7.6	0.290	0.295	0.298		
Е	13.85	14.1	14.35	0.544	0.555	0.565		
E1	9.3	9.4	9.5	0.365	0.37	0.375		
E2	7.3	7.4	7.5	0.286	0.292	0.294		
E3	5.9	6.1	6.3	0.231	0.24	0.247		
F		0.5			0.019			
G		1.2			0.047			
L	0.8	1	1.1	0.030	0.039	0.042		
R1			0.25			0.01		
R2		0.8			0.031			
Т	2 deg	5 deg	8 deg	2 deg	5 deg	8 deg		
T1		6 deg			6 deg			
T2		10 deg			10 deg			

 Table 7.
 PowerSO-10RF formed lead (gull wing) mechanical data

Note: Resin protrusions not included (max value: 0.15 mm per side)





Figure 7. Package dimensions



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Figure 8. **Tube information** 



# 5 Revision history

Table 8.Document revision history

Date	Revision	Changes		
07-Aug-2009	1	Initial release.		
23-May-2012	2	Updated V <sub>GS(Q)</sub> in <i>Table 4: Static</i> .		



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Doc ID 16087 Rev 2